

# MITSUBISHI HIGH SPEED CMOS M74HC02P/FP/DP

## QUADRUPLE 2-INPUT POSITIVE NOR GATE

### DESCRIPTION

The M74HC02 is a semiconductor integrated circuit consisting of four 2-input positive-logic NOR gates, usable as negative-logic NAND gates.

### FEATURES

- High-speed: 8ns typ. ( $C_L=15\text{pF}$ ,  $V_{CC}=5\text{V}$ )
- Low power dissipation:  $5\mu\text{W}/\text{package}$ , max ( $V_{CC}=5\text{V}$ ,  $T_a=25^\circ\text{C}$ , quiescent state)
- High noise margin: 30% of  $V_{CC}$ , min ( $V_{CC}=4.5\text{V}$ ,  $6\text{V}$ )
- Capable of driving 10 74LSTTL loads
- Wide operating voltage range:  $V_{CC}=2\sim 6\text{V}$
- Wide operating temperature range:  $T_a=-40\sim +85^\circ\text{C}$

### APPLICATION

General purpose, for use in industrial and consumer digital equipment.

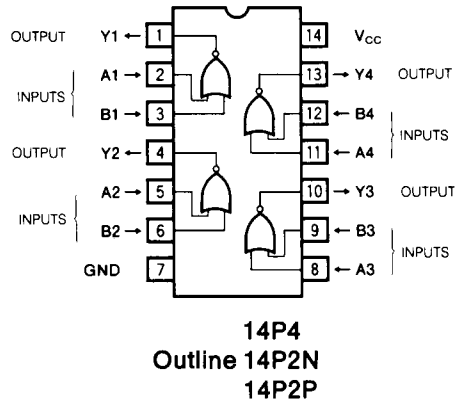
### FUNCTIONAL DESCRIPTION

Use of silicon gate technology allows the M74HC02 to maintain the low power dissipation and high noise margin characteristics of the standard CMOS logic 4000B series while giving high-speed performance equivalent to the 74LS02.

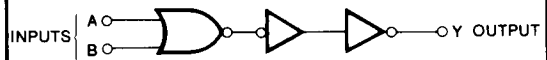
Buffered outputs Y improve input-to-output transfer characteristics and reduce to a minimum output impedance variations with respect to input voltage variations.

When both inputs A and B are low, the output Y will become high, and when at least one of the inputs is high, the output Y will become low.

### PIN CONFIGURATION (TOP VIEW)



### LOGIC DIAGRAM (EACH GATE)



### FUNCTION TABLE

| Inputs |   | Output |
|--------|---|--------|
| A      | B | Y      |
| L      | L | H      |
| H      | L | L      |
| L      | H | L      |
| H      | H | L      |

### ABSOLUTE MAXIMUM RATINGS ( $T_a = -40\sim +85^\circ\text{C}$ , unless otherwise noted)

| Symbol    | Parameter                      | Conditions        | Ratings               | Unit             |
|-----------|--------------------------------|-------------------|-----------------------|------------------|
| $V_{CC}$  | Supply voltage                 |                   | $-0.5\sim +7.0$       | V                |
| $V_i$     | Input voltage                  |                   | $-0.5\sim V_{CC}+0.5$ | V                |
| $V_o$     | Output voltage                 |                   | $-0.5\sim V_{CC}+0.5$ | V                |
| $I_{IK}$  | Input protection diode current | $V_i < 0\text{V}$ | -20                   | mA               |
|           |                                | $V_i > V_{CC}$    | 20                    |                  |
| $I_{OK}$  | Output parasitic diode current | $V_o < 0\text{V}$ | -20                   | mA               |
|           |                                | $V_o > V_{CC}$    | 20                    |                  |
| $I_o$     | Output current per output pin  |                   | $\pm 25$              | mA               |
| $I_{CC}$  | Supply/GND current             | $V_{CC}$ , GND    | $\pm 50$              | mA               |
| $P_d$     | Power dissipation              | (Note 1)          | 500                   | mW               |
| $T_{stg}$ | Storage temperature range      |                   | $-65\sim +150$        | $^\circ\text{C}$ |

Note 1 : M74HC02FP,  $T_a = -40\sim +60^\circ\text{C}$  and  $T_a = 60\sim 85^\circ\text{C}$  are derated at  $-6\text{mW}/^\circ\text{C}$ .  
M74HC02DP,  $T_a = -40\sim +50^\circ\text{C}$  and  $T_a = 50\sim 85^\circ\text{C}$  are derated at  $-5\text{mW}/^\circ\text{C}$ .

QUADRUPLE 2-INPUT POSITIVE NOR GATE

RECOMMENDED OPERATING CONDITIONS ( $T_a = -40 \sim +85^\circ\text{C}$ )

| Symbol     | Parameter                   | Limits                 |     |          | Unit             |
|------------|-----------------------------|------------------------|-----|----------|------------------|
|            |                             | Min                    | Typ | Max      |                  |
| $V_{CC}$   | Supply voltage              | 2                      |     | 6        | V                |
| $V_I$      | Input voltage               | 0                      |     | $V_{CC}$ | V                |
| $V_O$      | Output voltage              | 0                      |     | $V_{CC}$ | V                |
| $T_{opr}$  | Operating temperature range | -40                    |     | +85      | $^\circ\text{C}$ |
| $t_r, t_f$ | Input risetime, falltime    | $V_{CC} = 2.0\text{V}$ | 0   | 1000     | ns               |
|            |                             | $V_{CC} = 4.5\text{V}$ | 0   | 500      |                  |
|            |                             | $V_{CC} = 6.0\text{V}$ | 0   | 400      |                  |

ELECTRICAL CHARACTERISTICS

| Symbol   | Parameter                 | Test conditions  | Limits                    |                     |      |                    |                                 | Unit          |     |
|----------|---------------------------|--|---------------------------|---------------------|------|--------------------|---------------------------------|---------------|-----|
|          |                           |  | $V_{CC}(\text{V})$        | 25 $^\circ\text{C}$ |      |                    | -40 $\sim$ +85 $^\circ\text{C}$ |               |     |
|          |                           |  |                           | Min                 | Typ  | Max                | Min                             |               | Max |
| $V_{IH}$ | High-level input voltage  | $V_O = 0.1\text{V}$<br>$ I_O  = 20\mu\text{A}$                       | 2.0<br>4.5<br>6.0         | 1.5<br>3.15<br>4.2  |      |                    | 1.5<br>3.15<br>4.2              | V             |     |
| $V_{IL}$ | Low-level input voltage   | $V_O = 0.1\text{V}, V_{CC} = 0.1\text{V}$<br>$ I_O  = 20\mu\text{A}$ | 2.0<br>4.5<br>6.0         |                     |      | 0.5<br>1.35<br>1.8 | 0.5<br>1.35<br>1.8              | V             |     |
| $V_{OH}$ | High-level output voltage | $V_I = V_{IL}$   | $I_{OH} = -20\mu\text{A}$ | 2.0                 | 1.9  |                    | 1.9                             |               | V   |
|          |                           |  | $I_{OH} = -20\mu\text{A}$ | 4.5                 | 4.4  |                    | 4.4                             |               |     |
|          |                           |  | $I_{OH} = -20\mu\text{A}$ | 6.0                 | 5.9  |                    | 5.9                             |               |     |
|          |                           |  | $I_{OH} = -4.0\text{mA}$  | 4.5                 | 4.18 |                    | 4.13                            |               |     |
| $V_{OL}$ | Low-level output voltage  | $V_I = V_{IH}, V_{IL}$   | $I_{OL} = 20\mu\text{A}$  | 2.0                 |      |                    | 0.1                             | 0.1           | V   |
|          |                           |  | $I_{OL} = 20\mu\text{A}$  | 4.5                 |      |                    | 0.1                             | 0.1           |     |
|          |                           |  | $I_{OL} = 20\mu\text{A}$  | 6.0                 |      |                    | 0.1                             | 0.1           |     |
|          |                           |  | $I_{OL} = 4.0\text{mA}$   | 4.5                 |      |                    | 0.26                            | 0.33          |     |
|          |                           |  | $I_{OL} = 5.2\text{mA}$   | 6.0                 |      |                    | 0.26                            | 0.33          |     |
| $I_{IH}$ | High-level input current  | $V_I = 6\text{V}$  | 6.0                       |                     |      | 0.1                | 1.0                             | $\mu\text{A}$ |     |
| $I_{IL}$ | Low-level input current   | $V_I = 0\text{V}$  | 6.0                       |                     |      | -0.1               | -1.0                            | $\mu\text{A}$ |     |
| $I_{CC}$ | Quiescent supply current  | $V_I = V_{CC}, \text{GND}, I_O = 0\mu\text{A}$                       | 6.0                       |                     |      | 1.0                | 10.0                            | $\mu\text{A}$ |     |

QUADRUPLE 2-INPUT POSITIVE NOR GATE

SWITCHING CHARACTERISTICS ( $V_{CC} = 5V, T_a = 25^\circ C$ )

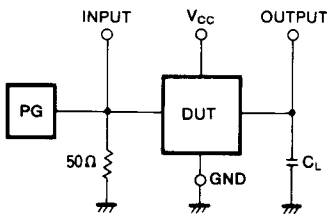
| Symbol    | Parameter  | Test conditions       | Limits |     |     | Unit |
|-----------|--|-----------------------|--------|-----|-----|------|
|           |  |                       | Min    | Typ | Max |      |
| $t_{TLH}$ | Low-level to high-level and high-level to low-level<br>output transition time  | $C_L = 15pF$ (Note 3) |        |     | 10  | ns   |
| $t_{THL}$ |  |                       |        |     | 10  |      |
| $t_{PLH}$ | Low-level to high-level and high-level to low-level<br>output propagation time |                       |        |     | 15  | ns   |
| $t_{PHL}$ |  |                       |        |     | 15  |      |

SWITCHING CHARACTERISTICS ( $V_{CC} = 2\sim 6V, T_a = -40\sim +85^\circ C$ )

| Symbol    | Parameter   | Test conditions       | Limits      |      |     |     |           |     | Unit |
|-----------|---|-----------------------|-------------|------|-----|-----|-----------|-----|------|
|           |   |                       | $V_{CC}(V)$ | 25°C |     |     | -40~+85°C |     |      |
|           |   |                       |             | Min  | Typ | Max | Min       | Max |      |
| $t_{TLH}$ | Low-level to high-level and<br>high-level to low-level<br>output transition time  | $C_L = 50pF$ (Note 3) | 2.0         |      |     | 75  |           | 95  | ns   |
|           |   |                       | 4.5         |      |     | 15  |           | 19  |      |
|           |   |                       | 6.0         |      |     | 13  |           | 16  |      |
| $t_{THL}$ | output transition time  |                       | 2.0         |      |     | 75  |           | 95  | ns   |
|           |   |                       | 4.5         |      |     | 15  |           | 19  |      |
|           |   |                       | 6.0         |      |     | 13  |           | 16  |      |
| $t_{PLH}$ | Low-level to high-level and<br>high-level to low-level<br>output propagation time |                       | 2.0         |      |     | 90  |           | 113 | ns   |
|           |   |                       | 4.5         |      |     | 18  |           | 23  |      |
|           |   |                       | 6.0         |      |     | 15  |           | 19  |      |
| $t_{PHL}$ | output propagation time   | 2.0                   |             |      | 90  |     | 113       | ns  |      |
|           |   | 4.5                   |             |      | 18  |     | 23        |     |      |
|           |   | 6.0                   |             |      | 15  |     | 19        |     |      |
| $C_i$     | Input capacitance   |                       |             |      | 10  |     | 10        | pF  |      |
| $C_{PD}$  | Power dissipation capacitance (Note 2)  |                       |             | 31   |     |     |           | pF  |      |

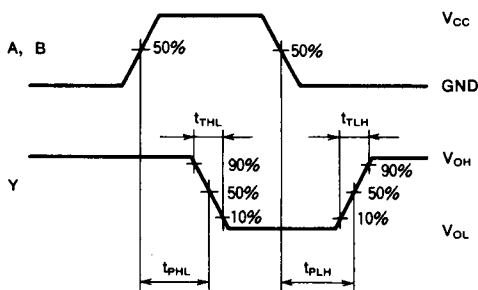
Note 2 :  $C_{PD}$  is the internal capacitance of the IC calculated from operation supply current under no-load conditions. (per gate)  
The power dissipated during operation under no-load conditions is calculated using the following formula:  
 $P_D = C_{PD} \cdot V_{CC}^2 \cdot f_i + I_{CC} \cdot V_{CC}$

Note 3 : Test Circuit



- (1) The pulse generator (PG) has the following characteristics (10%~90%):  $t_r = 6ns, t_f = 6ns$
- (2) The capacitance  $C_L$  includes stray wiring capacitance and the probe input capacitance.

TIMING DIAGRAM



**MITSUBISHI HIGH SPEED CMOS  
PACKAGE OUTLINES**

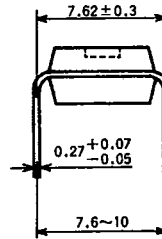
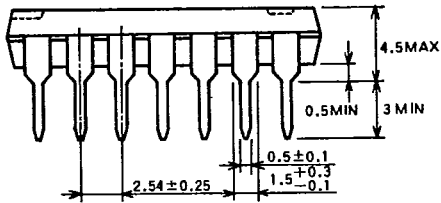
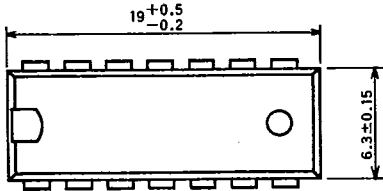
6249827 MITSUBISHI (DGTL LOGIC)

91D 12849

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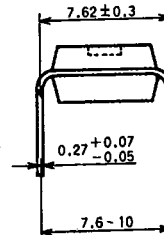
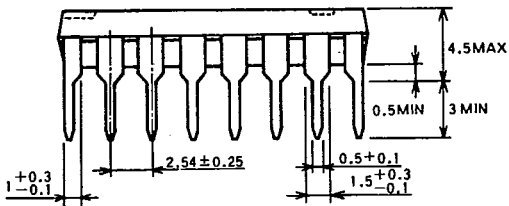
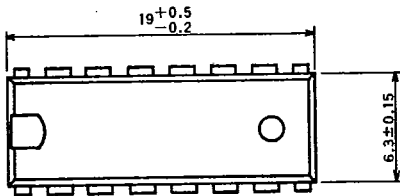
**TYPE 14P4 14-PIN MOLDED PLASTIC DIP**

Dimension in mm



**TYPE 16P4 16-PIN MOLDED PLASTIC DIP**

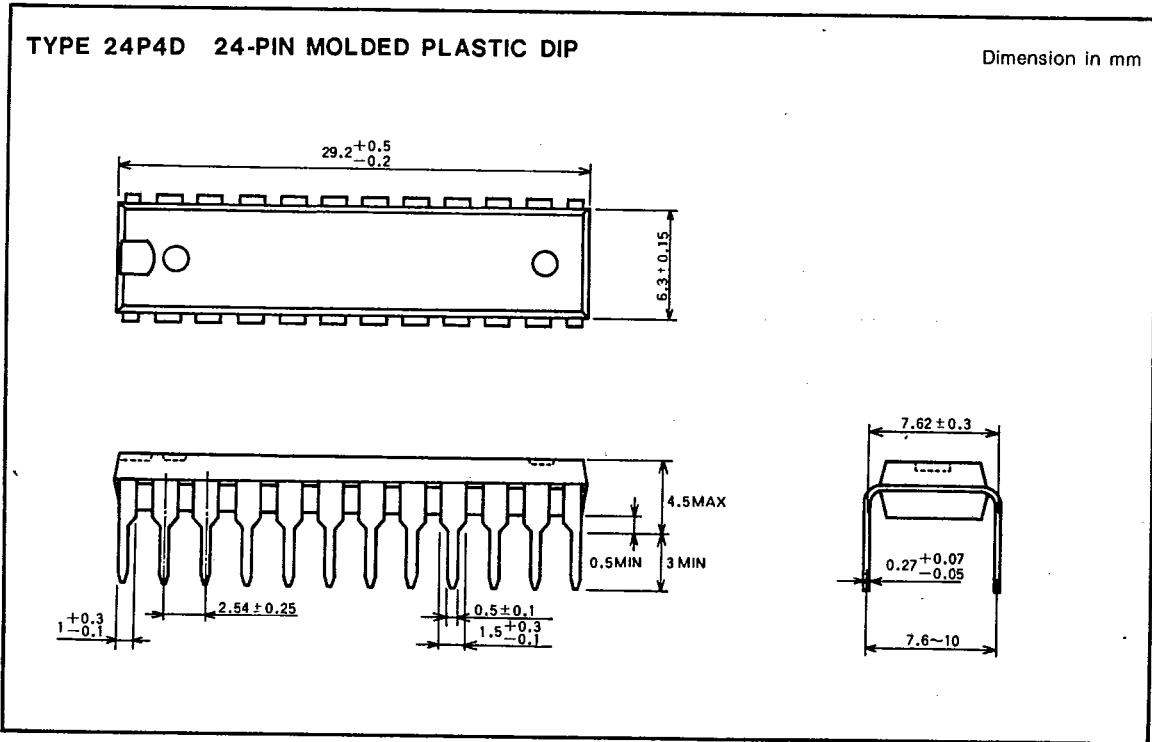
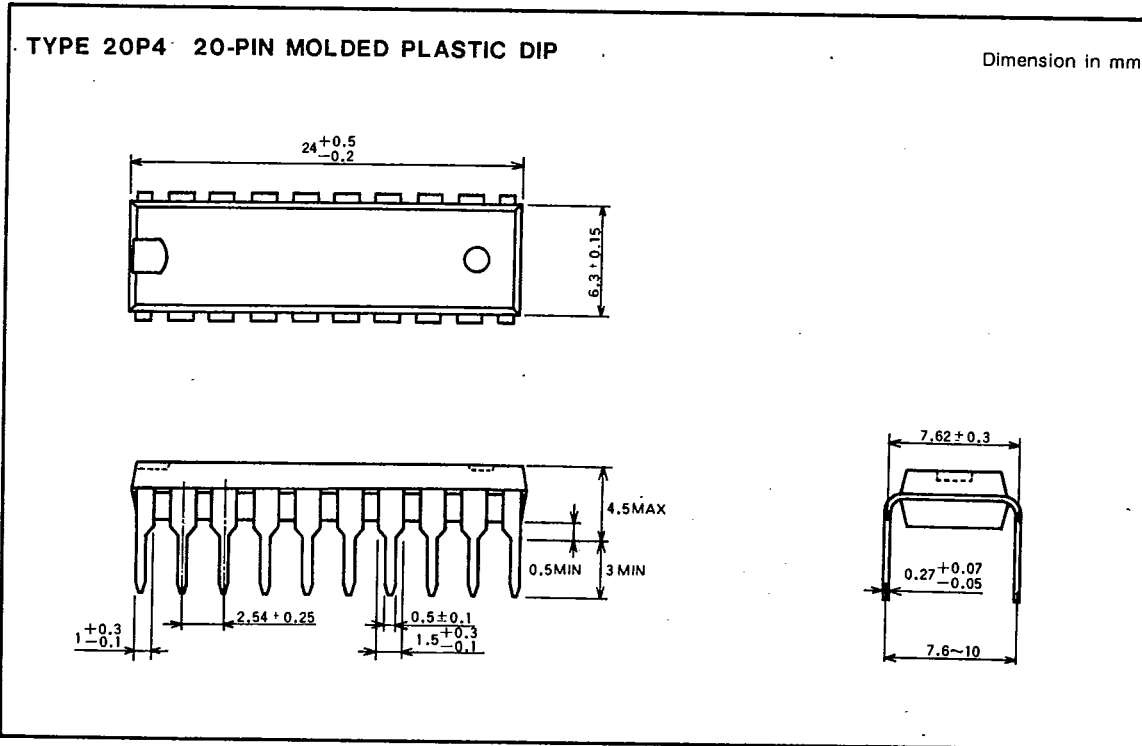
Dimension in mm



MITSUBISHI HIGH SPEED CMOS  
**PACKAGE OUTLINES**

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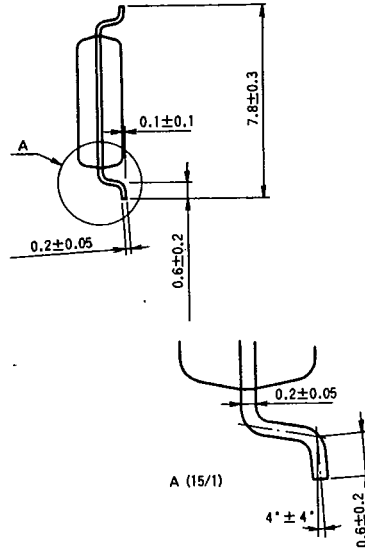
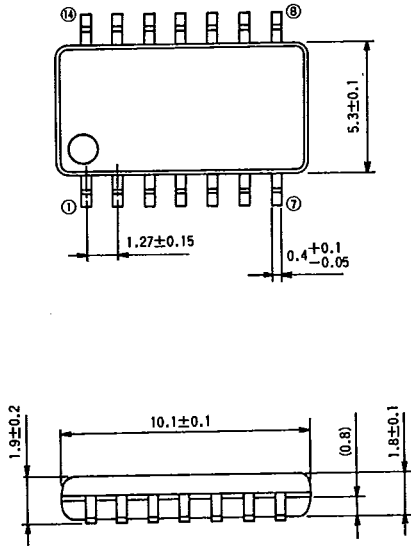
MITSUBISHI HIGH SPEED CMOS  
PACKAGE OUTLINES

6249827 MITSUBISHI (DGTL LOGIC)

91D 12851 D T-90.20

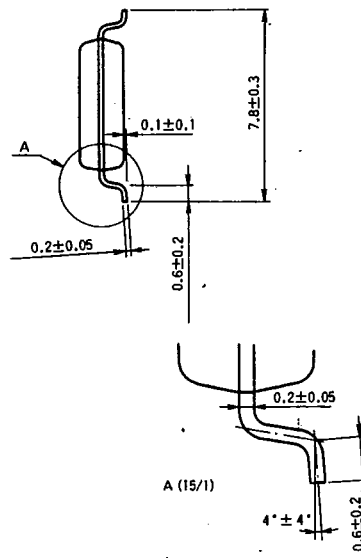
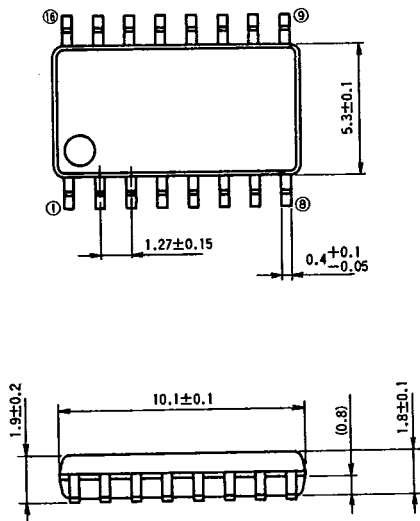
TYPE 14P2N 14PIN MOLDED PLASTIC SOP

Dimension in mm



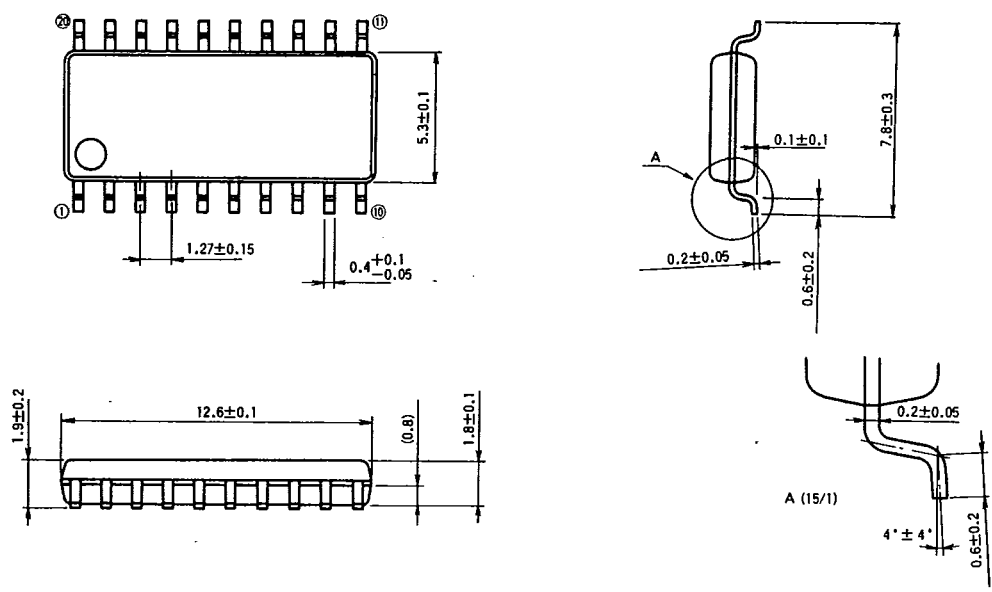
TYPE 16P2N 16PIN MOLDED PLASTIC SOP

Dimension in mm



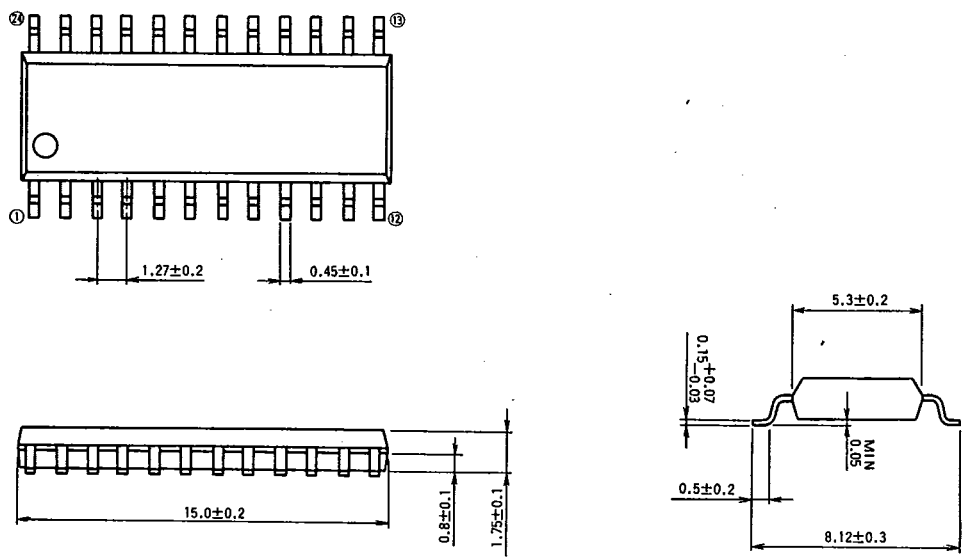
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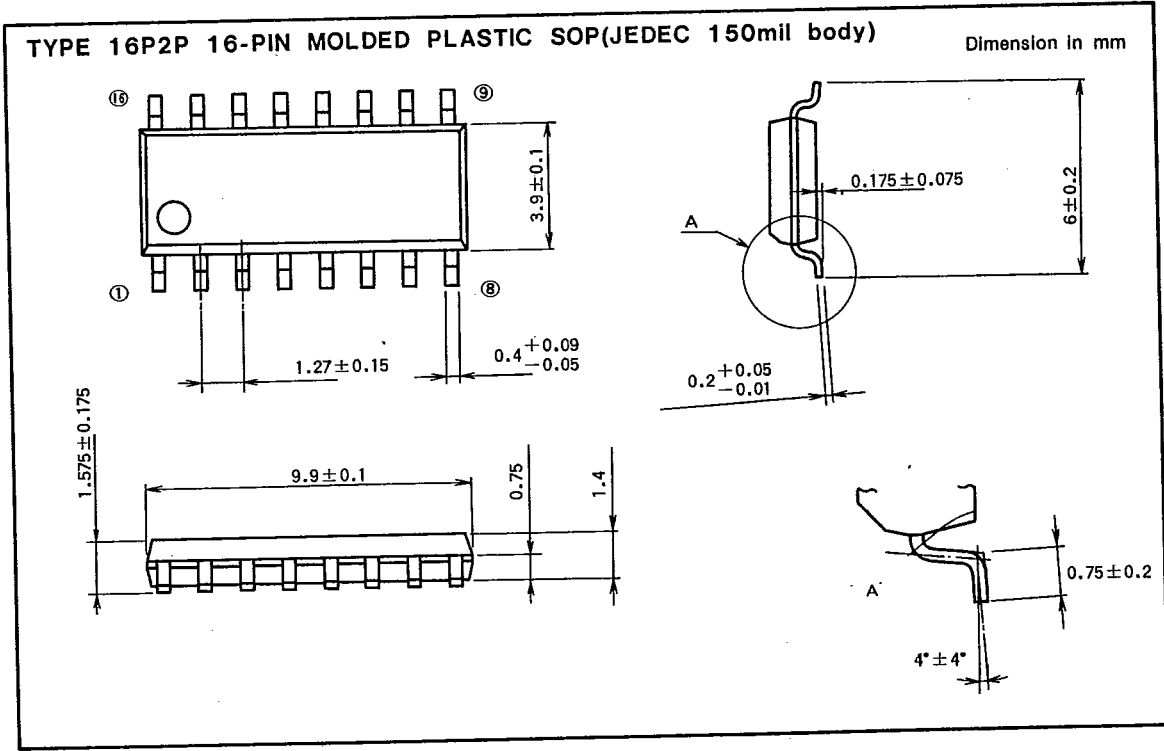
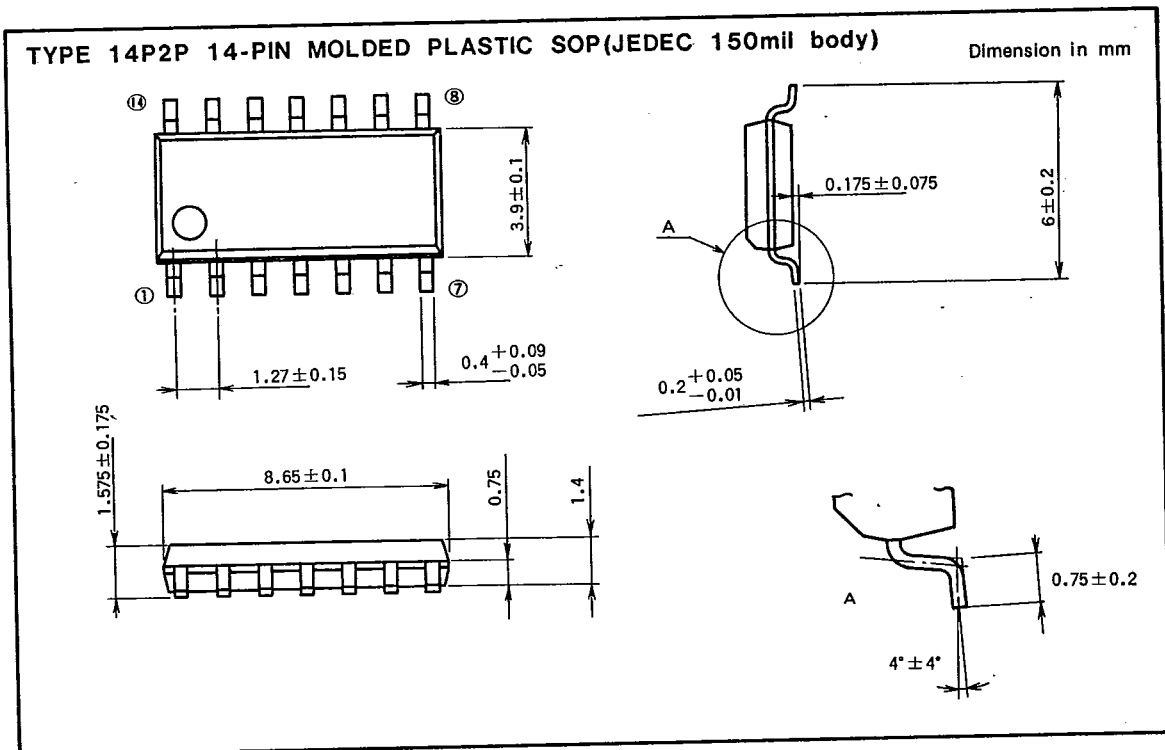
Dimension in mm



TYPE 24P2 24PIN MOLDED PLASTIC SOP

Dimension in mm





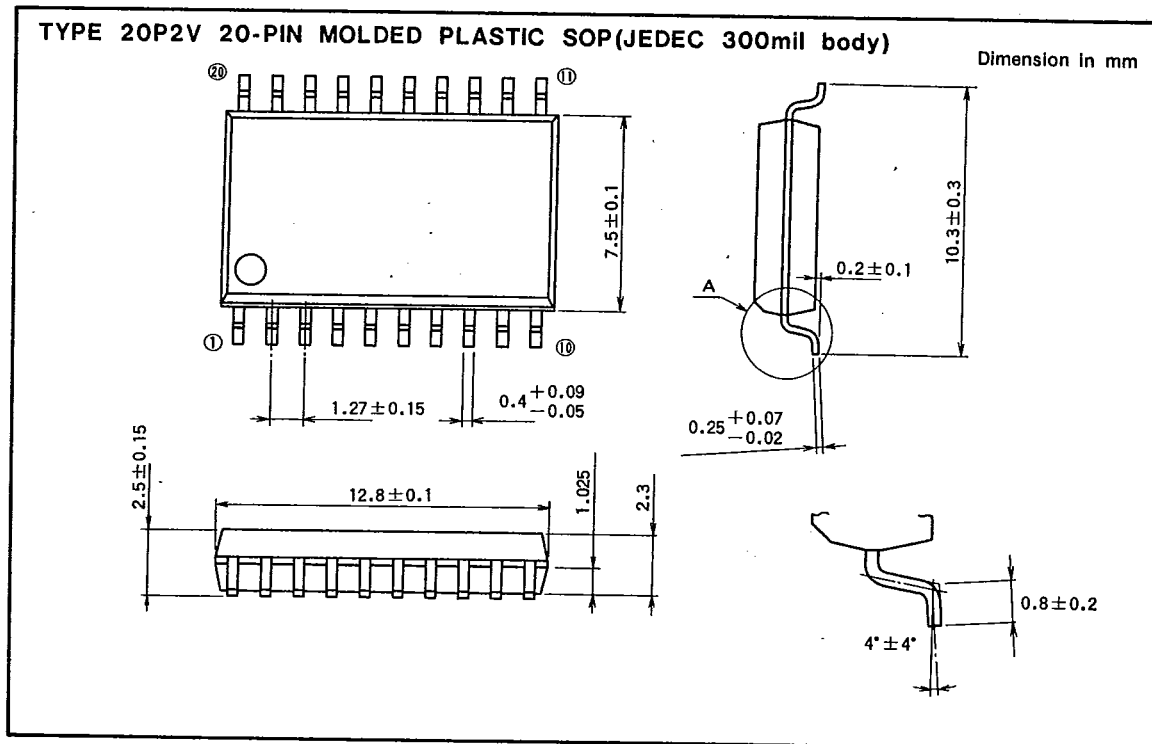
MITSUBISHI ELECTRIC CO.



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91D 12854 D T-90-20



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